Diode Semiconductor Device - Page 1 of 1



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## **Inclosure Material:**

Metal

**Overall Length:** 

2.300 inches

**Mounting Facility Quantity:** 

1

## Mounting Method:

Threaded stud

**Features Provided:** 

Hermetically sealed case

## **Overall Width Across Flats:**

Between 1.218 inches and 1.250 inches

Thread Size:

0.750 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

1200.0 reverse voltage, instantaneous and 1000.0 working peak reverse voltage, peak total value

## **Current Rating Per Characteristic:**

175.00 amperes average on-state current, 180 degrees conduction angle, average over a full 60-hz cycle

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius case

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

**Specification Data:** 

81349-mil-s-19500/211 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0